

Schottky Barrier Rectifier

DO-201AD

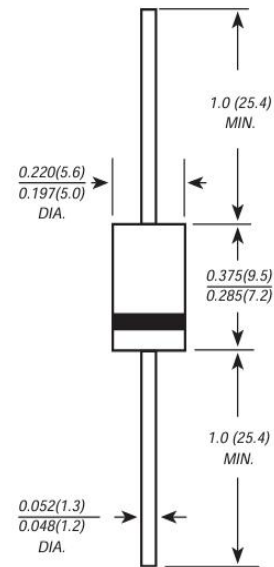
Parameter	Value	Unit
V_{RRM}	20~40	V
$I_{F(AV)}$	3.0	A

Features

- Low forward voltage drop
- High current capability
- High reliability
- High surge current capability

Maximum Ratings

- Operating Temperature: -55°C to +125°C
- Storage Temperature: -55°C to +125°C
- Maximum Thermal Resistance; 28°C/W Junction to Ambient



Dimensions in inches and (millimeters)

Catalog Number	Maximum Recurrent Peak Reverse Voltage	Maximum RMS Voltage	Maximum DC Blocking Voltage
1N5820	20V	14V	20V
1N5821	30V	21V	30V
1N5822	40V	28V	40V

Electrical Characteristics (at $T_J = 25^\circ\text{C}$ unless otherwise specified)

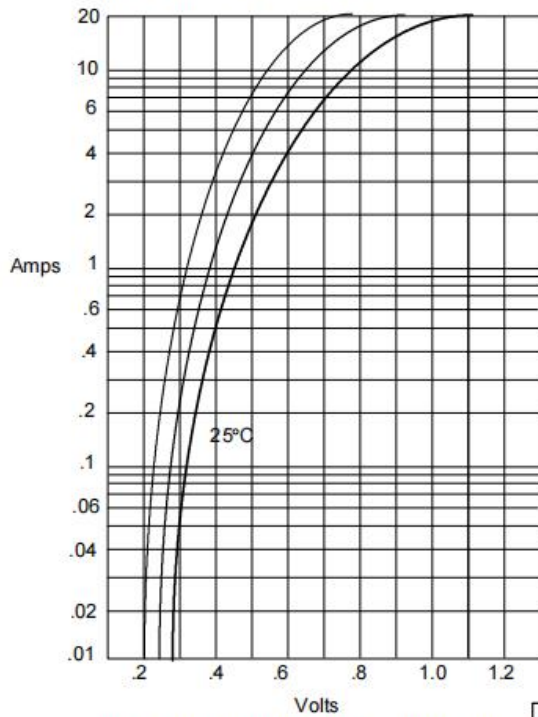
Parameter	Symbol	Value	Conditions
Average Forward Current	$I_{F(AV)}$	3.0A	$T_A = 85^\circ\text{C}$
Peak Forward Surge Current	I_{FSM}	80A	8.3ms, half sine
Maximum Instantaneous Forward Voltage	V_F	1N5820 475V	$I_F = 3.0\text{A};$ $T_A = 25^\circ\text{C}^*(\text{Note } 2)$
		1N5821 500V	
		1N5822 525V	
Maximum DC Reverse Current At Rated DC Blocking Voltage	I_R	0.5mA	$T_A = 25^\circ\text{C}$
		20mA	$T_A = 100^\circ\text{C}$
Typical Junction Capacitance	C_J	200pF	Measured at 1.0MHz, $V_R=4.0\text{V}$

Notes: 1. High Temperature Solder Exemption Applied, see EU Directive Annex 7.

2. Pulse test: Pulse width 300 μsec , Duty cycle 1%

Typical characteristics

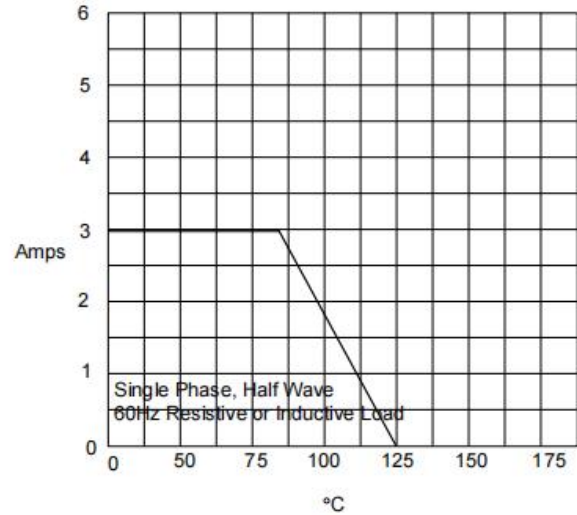
Figure 1
Typical Forward Characteristics



Instantaneous Forward Current - Amperes versus
Instantaneous Forward Voltage - Volts

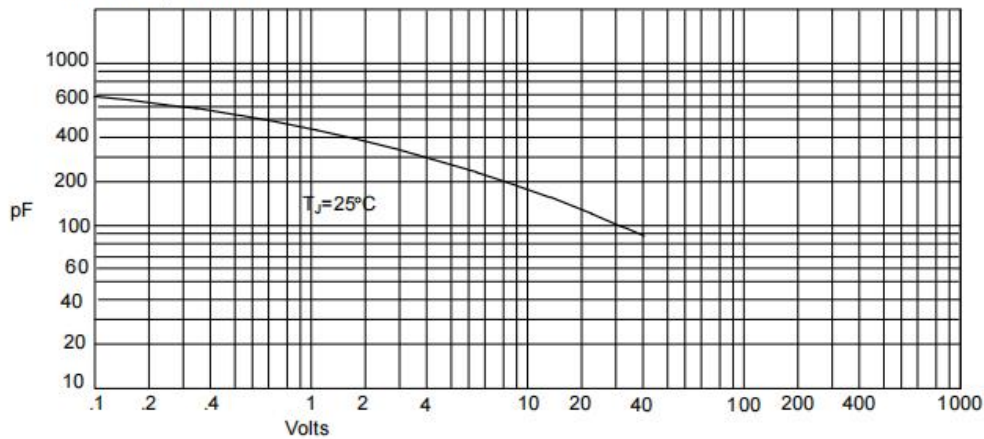
1N5820	_____
1N5821	_____
1N5822	_____

Figure 2
Forward Derating Curve

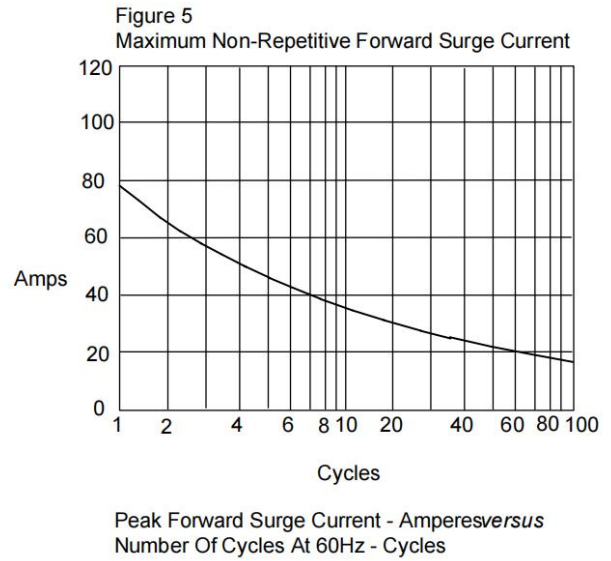
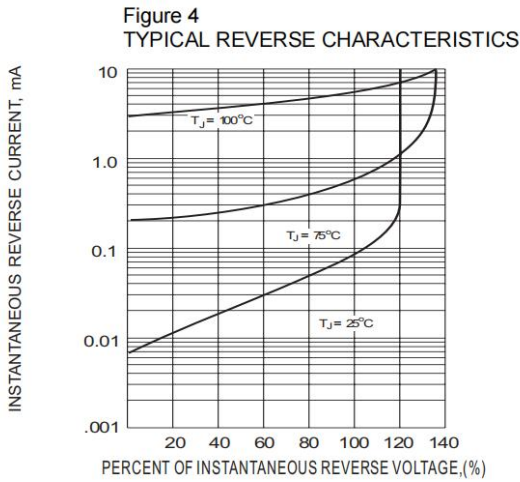


Average Forward Rectified Current - Amperes versus
Ambient Temperature - °C

Figure 3
Junction Capacitance



Junction Capacitance - pF versus
Reverse Voltage - Volts



***Important Usage Information and Disclaimer**

The specifications of Zhuhai Hypersemi Co., Ltd. products are not guarantees of product characteristics. They reflect typical performance expected in standard applications, which may vary with specific uses. Users must conduct prior testing for their applications and make necessary adjustments.

Users are responsible for the safety of applications utilizing our products and must implement adequate safety measures to prevent physical injury, fire, or other risks in case of product failure. It is the user's duty to ensure that application designs comply with all applicable laws and standards. Our products must not be used in any applications where a product failure could reasonably result in personal injury, unless specifically authorized in a signed document by Zhuhai Hypersemi Co., Ltd.

No representations or warranties are made regarding the accuracy or completeness of this information, including any claims of non-infringement of third-party intellectual property rights. Zhuhai Hypersemi Co., Ltd. assumes no liability for any applications or uses of its products and does not grant any licenses to its intellectual property rights or those of others. We also make no claims regarding non-infringement of third-party intellectual property rights that may arise from applications.

Due to technical requirements, our products may contain hazardous substances. For details, please contact your nearest sales office. This document replaces all previous information and may be updated. We reserve the right to make changes.